NSN 5961-01-392-9045

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View Online at https://aerobasegroup.com/nsn/5961-01-392-9045 **Inclosure Material:** Ceramic and metal **Overall Length:** 1.340 inches **Overall Height:** 0.160 inches **Overall Width:** 0.800 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Base **Mounting Method: Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.0 collector to base voltage/static/emitter open and 35.0 collector to emitter voltage/static/base open and 65.0 collector to emitter voltage, dc with base short-circuited to emitter and 4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 109.0 watts any acceptable absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Case contains beryllium oxide - handle and dispose iaw hazmat procedures; junction pattern arrangement: npn **Precious Material And Location:** Internal wire and metalized die and wire bond gold **Precious Material:** Gold **Test Data Document:** 13499-352-1550 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 case and 4 ribbon Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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